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FDT3N40 N-Channel UniFET[™] MOSFET

400 V, 2.0 A, 3.4

Features

- + $R_{DS(on)}$ = 3.4 Ω (Max.) @ V_{GS} = 10 V, I_D = 1.0 A
- Low Gate Charge (Typ. 4.5 nC)
- Low Crss (Typ. 3.7 pF)
- 100% Avalanche Tested

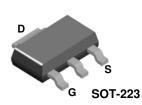
Applications

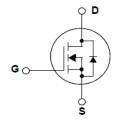
- LCD/LED TV
- Lighting
- Uninterruptible Power Supply



Description

UniFET[™] MOSFET is Fairchild Semiconductor[®]'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





Absolute Maximum Ratings

Symbol	Parameter Drain-Source Voltage			FDT3N40	Unit V	
V _{DSS}				400		
I _D	Drain Current	- Continuous (T _C = 25°C - Continuous (T _C = 100°		2.0 * 1.2 *	A A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	8.0 *	A	
V _{GSS}	Gate-Source voltage			±30	V	
E _{AS}	Single Pulsed Avalanche Energy		gle Pulsed Avalanche Energy (Note 2) 46		mJ	
I _{AR}	Avalanche Current		(Note 1) 2		A	
E _{AR}	Repetitive Avalanche Energy		(Note 1)	0.2	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5	V/ns	
P _D	Power Dissipation $(T_C = 25^{\circ}C)$ - Derate above 25^{C}			2 0.02	W W/°C	
T _{J,} T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
Τ _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

Thermal Characteristics

Symbol	Parameter	FDT3N40	Unit			
R_{\thetaJA}^{*}	Thermal Resistance, Case-to-Sink Typ.	60	°C/W			
* Surface Mounted on JESD51-3 Board, T<0.1sec.						

Device Marking		g Device				e Width 12mm		Quantity 4000		
FDT3	FDT3N40 FDT3N40TF SC									
Electrica	al Chai	racteristics T _c	= 25°C unle	ss otherwise no	ted	·				
Symbol	Parameter		Conditions		Min.	Тур.	Max	Unit		
Off Charact	teristics									
BV _{DSS}	Drain-Source Breakdown Voltage		$V_{GS} = 0V, I_D = 250 \mu A$		400			V		
ΔΒV _{DSS} / ΔΤ _J	Breakdow Coefficier	reakdown Voltage Temperature oefficient		$I_D = 250 \mu A$, Referenced to $25^{\circ}C$			0.4		V/°C	
I _{DSS}	Zero Gate Voltage Drain Current		$V_{DS} = 400V, V_{GS} = 0V$ $V_{DS} = 320V, T_{C} = 125^{\circ}C$				1 10	μΑ μΑ		
I _{GSSF}	Gate-Bod	dy Leakage Current, Forward		$V_{GS} = 30V, V_{DS} = 0V$				100	nA	
I _{GSSR}	Gate-Bod	ody Leakage Current, Reverse		$V_{GS} = -30V, V_{DS} = 0V$				-100	nA	
On Charact	eristics			•						
V _{GS(th)}	Gate Thre	hreshold Voltage		$V_{DS} = V_{GS}, I_D = 250 \mu A$		3.0		5.0	V	
R _{DS(on)}	Static Drain-Source On-Resistance		V _{GS} = 10V, I _D = 1A			2.8	3.4	Ω		
9 _{FS}	Forward Transconductance		$V_{DS} = 40V$, I _D = 1A	(Note 4)		2		S	
Dynamic C	haracteris	tics								
C _{iss}	Input Capacitance			V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz			173	225	pF	
C _{oss}	Output Capacitance Reverse Transfer Capacitance					30	40	pF		
C _{rss}						3.7	6	pF		
Switching (Characteri	istics								
t _{d(on)}	Turn-On I	Delay Time		$V_{DD} = 200V, I_D = 2A$ $R_G = 25\Omega$				10	30	ns
t _r	Turn-On I	Rise Time					30	70	ns	
t _{d(off)}	Turn-Off [Delay Time			1			10	30	ns
t _f	Turn-Off F	all Time				(Note 4, 5)		25	60	ns
Qg	Total Gate	e Charge		$V_{DS} = 320$				4.5	6	nC
Q _{gs}	Gate-Sou	irce Charge		$V_{GS} = 10V$			1.2		nC	
Q _{gd}	Gate-Dra	in Charge		(Note 4, 5)				2		nC
Drain-Sour	ce Diode (Characteristics and I	Maximun	n Ratings						•
I _S	Maximum Continuous Drain-Source Dioo			de Forward	Current				2	Α

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(Note 4)

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210

0.75

8

1.4

А ٧

ns

μC

NOTES:

 I_{SM}

 V_{SD}

t_{rr}

Q_{rr}

1. Repetitive Rating: Pulse width limited by maximum junction temperature

Drain-Source Diode Forward Voltage

Maximum Pulsed Drain-Source Diode Forward Current

2. L = 10mH, I_{AS} = 2A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^\circ C$

Reverse Recovery Time

Reverse Recovery Charge

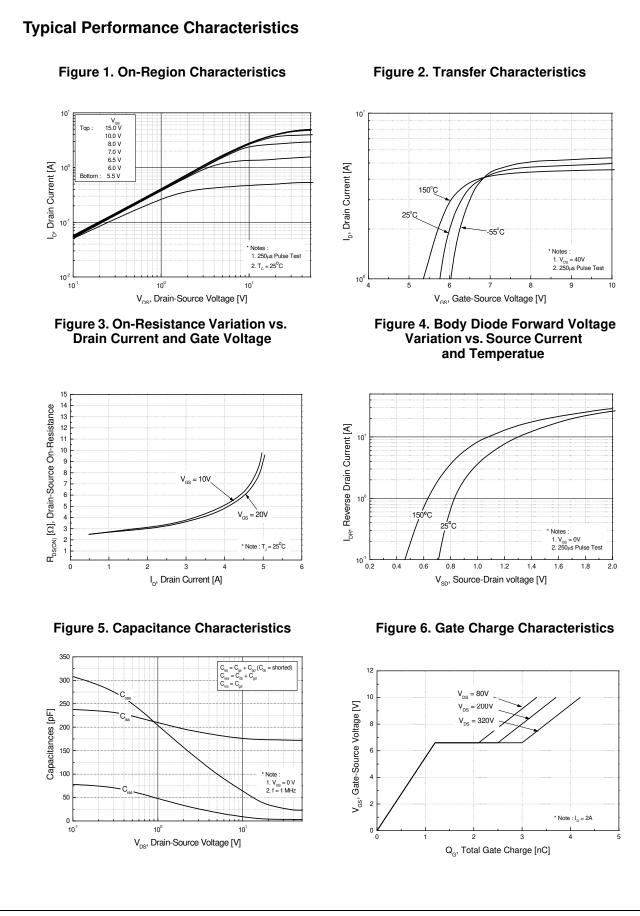
3. $I_{SD} \leq 2A, \, di/dt \leq 200A/\mu s, \, V_{DD} \leq BV_{DSS}, \, Starting \, T_J$ = 25°C

4. Pulse Test: Pulse width $\leq 300 \mu s,$ Duty Cycle $\leq 2 \%$

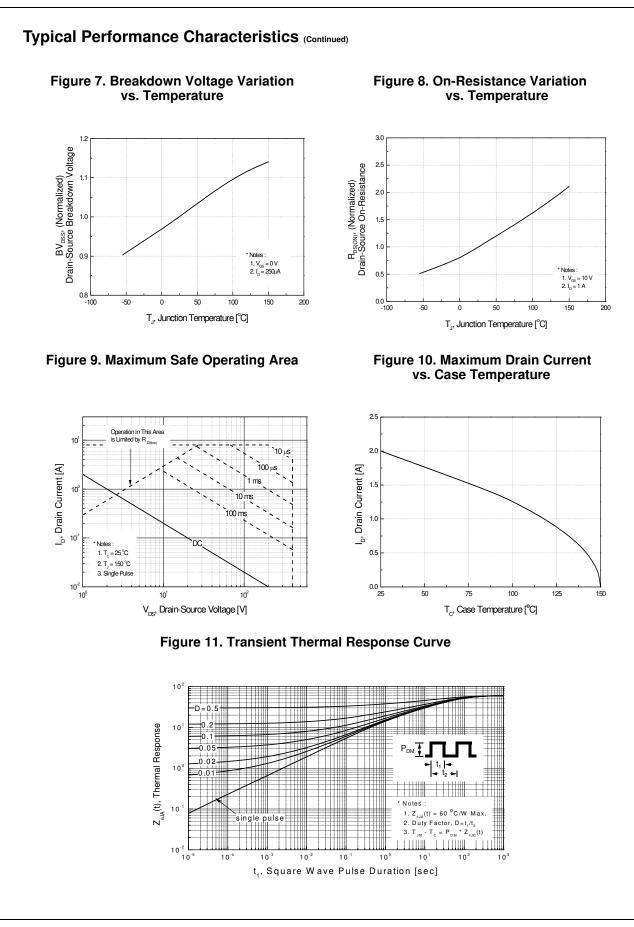
5. Essentially Independent of Operating Temperature Typical Characteristics

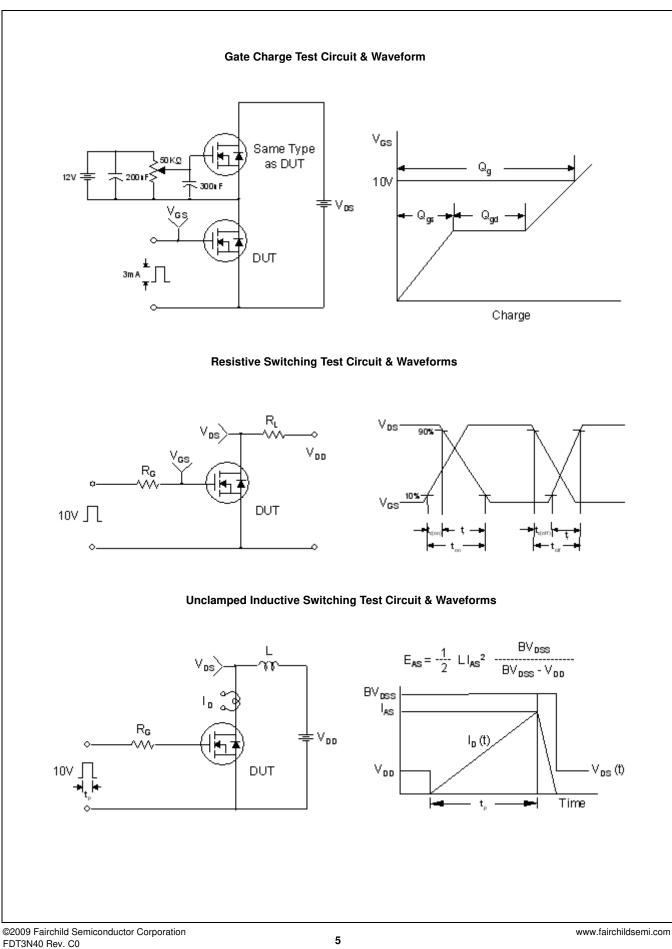
 $V_{GS} = 0V, I_S = 2A$

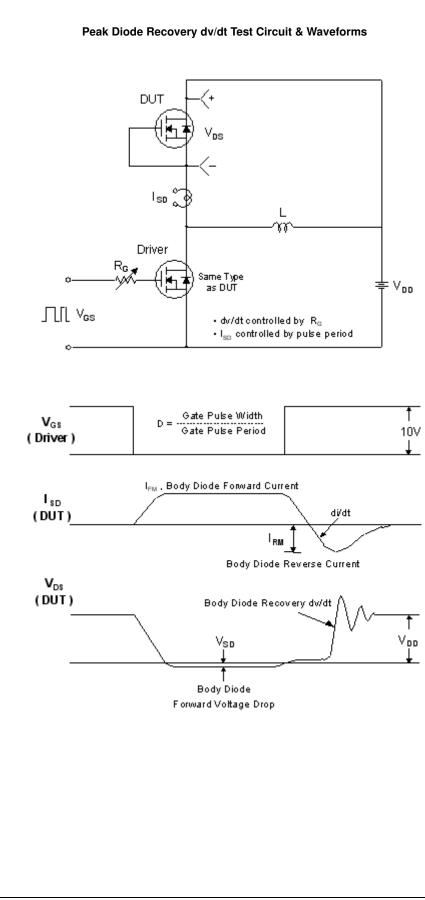
 $V_{GS} = 0V, I_S = 2A$ dI_F/dt =100A/µs

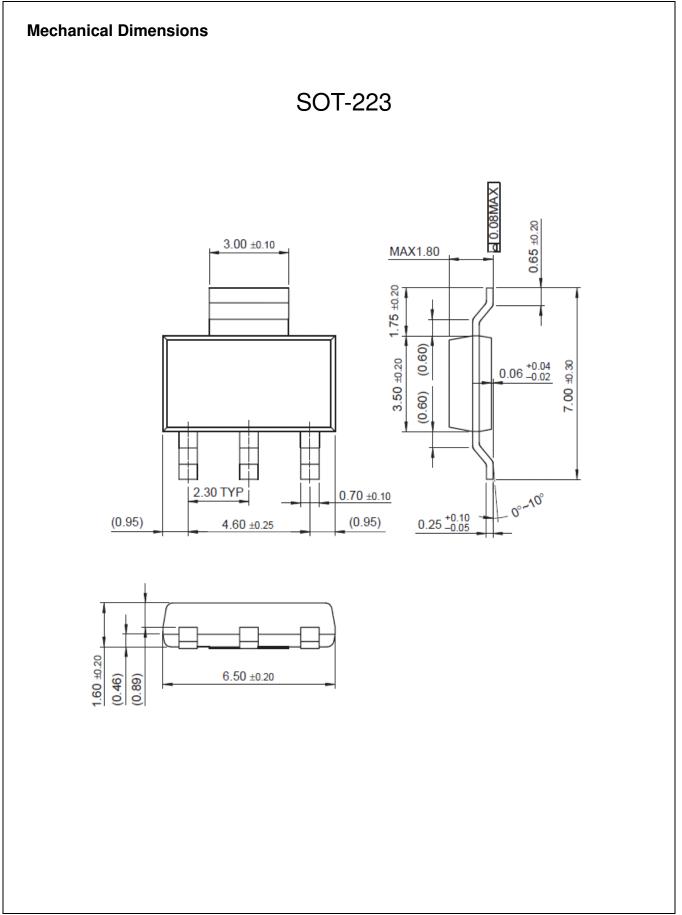


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·		Rev.		

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